Ferrom agnetic \ '-junctions

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We investigate Josephson coupling through a ferrom agnetic thin Im using Superconductor-Insulator-Ferrom agnet-Superconductor planar junctions. D am ped oscillations of the critical current are observed as a function of the ferrom agnetic layer thickness. We show that they result from the exchange energy gained or lost by a quasiparticle Andreev-re ected at the ferrom agnetsuperconductor interface. The critical current cancels out at the transition from positive ("0") to negative (" ") coupling, in agreem ent with theoretical calculations.

Current can ow without dissipation through a thin insulating layer or a weak link separating two superconductors. Because of the quantum character of the superow a phase di erence, , between the superconductors

appears. The current-phase relationship of the link is a periodic function of . For a tunnel barrier, as rst found by Josephson, [1] it is given by $I = I_c \sin()$, where I_c is the critical current. In this Letter, we show that I_c can change sign when the superconductors are coupled via a thin ferrom agnetic layer. Referring to the Josephson current-phase relationship, this change corresponds to a

-phase shift of . Thus Josephson junctions presenting a negative coupling are usually called -junctions. We speci cally observe the transition from a positive to a negative coupling or equivalently from "0" to " " junctions by increasing the ferrom agnetic layer thickness.

The possibility of a negative Josephson coupling was rst raised by Kulik [2]. It is due to the spin- ip of the electrons forming a Cooperpair when tunneling through an insulator. The spin- ip originates from the electron exchange interaction with uncorrelated magnetic in purities in the barrier. This channel, which coexists with direct tunneling, is suggested to reduce the critical current of the junction. W hether or not spin- ip tunneling can overtake direct tunneling, leading to a negative critical current, rem ains uncertain.

M ore recently Buzdin et al. [3] showed that in ballistic Superconductor/Ferrom agnet/Superconductor weak links (S/F/S), I_c displays dam ped oscillations as a function of d_F , the thickness of F . C lose to the critical tem perature of the superconductor an analytical expression of I_c is available. They found I_c / sin $_F = _F$, where $_{\rm F}$ = 2E $_{\rm ex}$ d $_{\rm F}$ = hy . E $_{\rm ex}$ is the exchange energy and v $_{\rm F}$ the Fermi velocity in F.W hen $_{\rm F}$ is greater than and smaller than 2 , I_c is negative leading to a -coupling. Physically, this is a consequence of the phase change of the pair function induced in F by the proxim ity e ect [4]. In fact, energy conservation requires that a C ooper pair entering into the ferrom agnet receives a nite mom entum, $p = hv_{\rm f} = 2E_{\rm ex}$, from the spin splitting of the up and down bands [5]. By quantum mechanics, pmodies the phase, = p x, of the pair wave function that increases linearly with the distance, x, from the S/F interface. If all pair trajectories and spin con gurations are

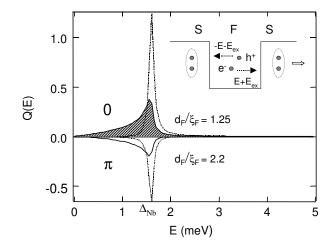


FIG.1: Spectral current density, Q (), as a function of energy for SFS (fullline) and SIFS (dashed line) Josephson junctions. Q () is calculated from the U sadel equations 9 for two di erent $d_F = {}_F$ ratios. The "0" ($d_F = {}_F = 1.8$) and " " ($d_F = {}_F = 3$) couplings result from positive (dashed area) and negative integrals respectively. The inset illustrates the transfer m echanism for C ooper pairs through F by Andreev re-ections.

taken into account, the amplitude of the superconducting order parameter in F is given by sin ()= [5]. When F is coupled to a second superconductor through a weak link, the Josephson critical current is proportional to the pair amplitude in F and hence to sin $_{\rm F} = _{\rm F}$.

M icroscopically the transfer of C ooper pairs through the ferrom agnet occurs via Andreev rejections [6]. An electron-like excitation in F with energy lower than the superconducting energy gap, , cannot enter into the superconductor. It is rejected at the F/S interface as a hole and it is then rejected back as an electron at the opposite S/F interface as illustrated in the inset of Fig. 1 [7]. The constructive interference of the electron-like and hole-like excitations gives rise to Andreev bound states (ABS) in F, which carry the supercurrent. The same m echanism accounts for the Josephson coupling through a norm alm etal [7], but in a ferrom agnet the spectrum of the ABS is a ected by the spin splitting of the spin bands as the Andreev rejections reverse the spin of the quasiparticles [8]. Therefore the spectral current density, Q () that de nes the current density per bound state in F is a function of the exchange energy, E_{ex} . In the dirty lim it, Q () can be obtained by solving [9] the U sadel equations [10]. The exponential decay of the order parameter in F on a length scale given by $_{\rm F}$ = $^{-}$ hD =2E_{ex}, the coherence length in F, allows use of the "long junction" approximation [11], in which the thickness of the ferrom agnetic layer, $d_{\rm F}$, is on the order of $_{\rm F}\,$ and D $\,$ is the di usion constant. W hen the energy gap is sm aller than E_{ex} and the Thouless energy $E_{Th} = hD = d_{t}^{2}$, as in the experim ent described below, the energy dependence of Q () is basically xed by the BCS superconducting density of states. Therefore, the spectral current density is peaked at the superconducting energy gap. It is either positive or negative for $E_{ex} < 9^2 = 16E_{Th}$ (i.e. $d_F < 3 = 4_F$) or $E_{ex} > 9^{-2} = 16E_{Th}$ (i.e. $d_F > 3 = 4_F$) respectively as shown in Fig. 1. The critical current I_c at zero tem perature is obtained by integrating Q (); for $d_F = F >> 1$, $I_c = 321 = R_n d_F = F exp d_F = F sin = 4 + d_F = F$ as found by Buzdin [12]. Thus, we recover quantitatively the behavior illustrated above.

Experimentally, since the coherence length in F is very small ($_{\rm F}$ ' 30 A, as shown below) the sim – plest way to measure the critical current is to fabricate planar junctions where a thin insulating barrier is inserted between the superconducting counterelectrode and the ferrom agnet. The tunnel barrier raises the junction resistance, R_n , low ering I_c to measurable values (typically 10-100 A). In a Superconductor/Insulator/Ferrom agnet/Superconductor (SIFS) Josephson junction the energy spectrum of the Andreev bound states in F is modi ed by the insulating layer [13]. However, the current spectral density reported in Fig. 1 shows the same general behavior as observed in SFS junctions, including the change of sign of the Josephson critical current as a function of the ferrom agnetic layer thickness.

Planar N b=A l=A l₂O 3=P dN i=N b junctions were fabricated by e-gun thin Im evaporation in a typical base pressure of 10 9 Torr, rising to 10 8 Torr during deposition. The lm thickness was monitored during grow th to better than 1 A by a quartz balance. The junction had the standard four term inal cross-geometry [4], de ned during evaporation by shadow masks. A Siwafer was rst covered by 500 A of SiO. Then, a 1500 A thick Nb strip was evaporated and backed by 500 A of Al. The critical tem perature of the Nb strip was 9.2 K and its residual-resistance-ratio ratio about 4. The Alsurface oxidation was performed in a glow discharge during 1 m in, and completed in a 10 Torr oxygen atm osphere during 2 min. A square window of 1mm 1mm left in a 500 A thick SiO layer deposited on the Alde ned the junction area. Eight junctions were aligned on the same Nb/Al strip. A PdN i strip (thickness 40-150 A) perpendicular

to the Nb/Al strip was then evaporated on each junc-

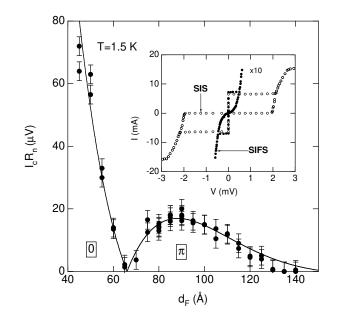


FIG.2: Josephson coupling as a function of thickness of the PdN i layer (full circles). The critical current cancels out at d_F ' 65 A indicating the transition from "0" to " "-coupling. The full line is the best t obtained from the theory (eqn.(1)) as described in the text. Inset shows typical I-V characteristics of two junctions with (full circles), and without (empty circles) PdN i layer.

tion and covered by a 500 A thick Nb counter-electrode (T_c = 8.7 K). The junction resistance varied from 50 m to 400 m . The entire process was carried out without breaking the vacuum in the deposition chamber. The Ni concentration was about 12 % as checked by Rutherford Backscattering Spectrom etry on sam ples evaporated at the same time. At this concentration, the PdNi is an itinerant ferrom agnet [14], whose the Curie tem perature is about 100 K. The junction was polarized by an ac current, the I-V characteristics being monitored on a digital commercial oscilloscope set in the X-Y mode and directly recorded from the oscilloscope. Measurem ents were performed down to 1.5 K; the minimum detectable value of I_c was about 1 A. A -m etal shield reduced the residual magnetic eld on the sam ple to 10² G auss.

The N b=A l=A $l_{2}O_{3}$ =N b junctions without a ferrom agnetic layer showed high quality tunneling. At low tem – perature the Nb/A l bilayer is a hom ogeneous superconductor. The I-V characteristic is hysteretic as expected for SIS junctions [15]. The subgap conductance at 1.5 K is only 10⁴ of the high energy conductance corresponding to negligible current leakage as shown in the inset of Fig. 2. The I_cR_n product is 1.25 mV with junction to junction uctuations of at most 15 %. The inset of Fig. 2 also shows the I-V characteristics of a Nb/A l/A $l_{2}O_{3}$ /PdN i/Nb junction with a thin layer of PdN i (d_F = 50 A). The critical current is strongly reduced while the subgap conductance is enhanced. B oth

e ects result from the suppression of the order param eter in F by the exchange ekd. The superconducting correlations are so e ciently reduced at the A $l/A l_2O_3/P dN i$ interface [4] that the dissipative branch of the I-V curve re ects the energy dependence of the density of states in the N b/A l bilayer.

The Josephson coupling, $I_c R_n$, as a function of the thickness of the ferrom agnetic layer is presented in the main body of Fig. 2. We chose this representation to elim inate uctuations in the critical current that are sim ply due to uctuations in the junction resistance. For each value of d_F , the $I_c R_n$ product of two di erent junctions is reported, with typical sample to sample variations of less than 10 % , illustrating the reproducibility of the junction fabrication technique. The Josephson coupling is of the order of 10-20 V, i.e. 100 times lower that that measured on junctions without PdN i. The sign of I_c cannot be determ ined from the I-V characteristics and the transition from "0" to " " coupling is revealed as a zero of the $I_c R_n$ product. The latter occurs at d_F ' 65 A, consistent with our recent m easurem ents of the density of states in F [4]. Fig. 2 also shows the best t to the theory in which the $I_{\rm c}R_{\rm n}$ product is obtained by integrating the spectral current density found solving the Usadel equations for a SIFS junction (see Fig. 1) :

$$I_{c}R_{n} = \frac{1}{2 e} \frac{1}{e} \frac{\cos \frac{d_{F}}{F} \cosh \frac{d_{F}}{F} + \sin \frac{d_{F}}{F} \sinh \frac{d_{F}}{F}}{\cos^{2} \frac{d_{F}}{F} \cosh^{2} \frac{d_{F}}{F} + \sin^{2} \frac{d_{F}}{F} \sinh^{2} \frac{d_{F}}{F}}$$
(1)

where $_{\rm b}$ is the PdN i/Nb interface resistance. The Josephson coupling decreases linearly with $_{\rm b}$ as do the number of Andreev rejections at the S/F interface [16]. The tting parameters are $_{\rm b}$ = 5:3 and $_{\rm F}$ = 28A. The interface resistance is the same as that deduced from the thickness dependence of the zero energy density of states [4], while the coherence length in PdN i is smaller possibly because of the few per cent increase in the N i concentration. The corresponding exchange energy is $E_{\rm ex}$ = 35m eV, taking $v_{\rm F}$ = 2 10⁷cm =s and the mean free path in the PdN i equal to d_F as found by resistivity m easurements on bare PdN i thin lm s.

In Fig. 3 the critical current, I_c as a function of the magnetic ux is presented for (i) a junction without PdN i and (ii) three junctions with di erent thickness of PdN i but roughly the same I_cR_n product. One of the latter gives "0" coupling (60 A) and two " " coupling (90 A and 110 A). The di raction patterns are those expected for a square junction with hom ogeneous current density [15] provided a small m isorientation of 7 between the eld direction and one edge of the junction is included (see t in Fig. 3). The critical current cancels out when an integer of ux quanta settles into the junction. A sthe

eld penetrates in a volum e whose cross-section is given by w (2 + d_F), where is the penetration depth and w=1 mm the junction width, an estimate of for H=0.2

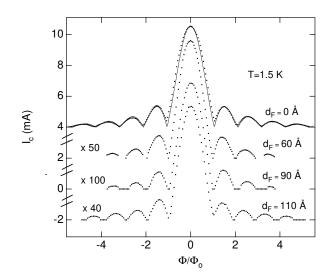


FIG. 3: Critical current as a function of magnetic ux for four di erent junctions, three with and one without PdN i. The data are shifted vertically for clarity. The full line is the Fraunhofer pattern expected for a square junction with hom ogeneous current density and a m isalignment of 7 between the eld and the junction edge. The junctions with PdN i have about the same coupling. The di raction patterns are not a ected by the PdN im agnetization.

G auss corresponding to the rst quantum ux, is = 500 A, consistent with the value expected for Nb thin Im s [15]. Importantly, the maximum critical current occurs at zero applied eld independently of the ferrom agnetic layer thickness. This shows that the Josephson coupling presented in Fig. 2 is indeed the maximum coupling as assumed. It also indicates that the eld produced by the thin PdN i Im falls o rapidly in the superconductor when one moves away from the S/F interface. Therefore no orbital dephasing is generated in S by the ferrom agnetic layer which acts only through the spin degree of freedom as expected in the Pauli lim it [17].

The tem perature dependence of the critical current is found by integrating the spectral current density, Q () multiplied by the distribution function [9]. Far from d_F ' 3 = 4 $_F$, where the critical current cancels out, I_C is mainly determined by the temperature dependence of the density of states on each side of the junction. As the energy dependence of the density of states in the Aland PdN i is not exactly the BCS density of states, the tem perature dependence of I_c shows a more linear behavior [18] than that originally found by Ambegaokar-Barato [19] for two bulk superconductors separated by a tunnel barrier. This linear behavior is shown in Fig. 4 where the tem perature dependence of the norm alized critical current for three junctions with di erent PdN ithickness is reported ($d_F = 50A$ for "0" coupling, $d_F = 80A$ for " coupling and $d_F = 70A$ near the transition). The critical current of the junction with a 70A thick PdNi layer is too sm all to be measured at T > 5K.

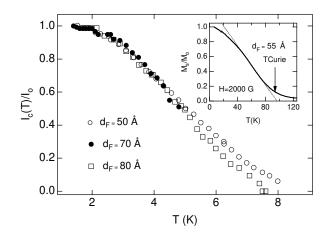


FIG. 4: Normalized temperature dependence of the critical current for three di erent PdN i thicknesses. Note linear dependence expected for Superconductor-Insulator-Normal-Superconductor tunnel junction 18. Inset shows normalized saturation magnetization as a function of temperature, measured via anomalous Halle ect for a bare PdN ithin Im.

W hen d_F $\,$ ' 3 =4 $_{\rm F}$, where the critical current cancels, the spectral current density Q (), changes sign as a function of energy. Thus, changing the occupation of the ABS by raising the temperature allows to shift the spectral weight from a positive to a negative current density or equivalently from forward to back-ward ABS. This results in a tem perature induced "0-junction"-" junction" transition as recently observed in SFS junctions [20]. Such a transition only occurs for junctions very close to the critical point and it requires a $I_c R_n$ product lower than 1 V. Because of their much smaller junction resistance, SFS junctions are more suitable than SFS to investigate sm all Josephson coupling. In fact, the m in im um $I_c R_n$ product m easurable in our junctions is as low as a few V and hence too large to reveal a sign change. As a nalcheck we measured the temperature dependence of the saturation m agnetization of bare P dN i thin $\ln s (q = 40-150 \text{ A})$ via the anom alous Halle ect [21]. As shown in the inset of Fig. 4 for $d_F = 55$ A the norm alized saturation m agnetization , M $_{s}=M_{0}$, which is proportional to the Hall signal at H = 2000 G auss, show s very sm all variations at low tem perature (T < 10 K) corresponding to a few percent change in M_s. Thus the long range magnetic order at low tem perature is well de ned and the sm all change in M $_{\rm s}$ has negligible e ects on the critical current tem perature dependence.

In summary, we have shown that the critical current of SIFS Josephson junction is an oscillating function of the thickness of the ferrom agnetic layer. The zero of the critical current obtained for d_F ' 3 =4 $_F$ indicates

a change of sign of I_c , leading to "-coupling". This is a consequence of the superconducting order parameter oscillations induced in the ferrom agnet by the proxim ity e ect as recently observed by tunneling spectroscopy [4]. Such ferrom agnetic-based "-junctions" m ay represent a new element in the architecture of novel quantum devices as recently suggested [22].

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